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Enhanced photoelectrochemical properties of TiO₂ nanorod arrays decorated with CdS nanoparticles

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Abstract

 TiO_2 nanorod arrays (TiO_2 NRAs) sensitized with CdS nanoparticles were fabricated via successive ion layer adsorption and reaction (SILAR), and TiO_2 NRAs were obtained by oxidizing Ti NRAs obtained through oblique angle deposition. The TiO_2 NRAs decorated with CdS nanoparticles exhibited excellent photoelectrochemical and photocatalytic properties under visible light, and the one decorated with 20 SILAR cycles CdS nanoparticles shows the best performance. This can be attributed to the enhanced separation of electrons and holes by forming heterojunctions of CdS nanoparticles and TiO_2 NRAs. This provides a promising way to fabricate the material for solar energy conversion and wastewater degradation.

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Keywords: TiO₂ NRAs, OAD, CdS NPs, photoelectrochemistry, photocatalyst, visible light

1. Introduction

Since the first report of photocatalytic splitting of water using titanium dioxide (TiO₂) photoanode by Fujisima and Honda in 1972 [1], TiO₂ has been extensively studied and has been considered a superior candidate for solving environmental concerns owing to its low cost, photostability, chemical inertness, nontoxicity, and strong photocatalytic activity [2]. However, the widespread applications of TiO₂ are limited due to its large band gap (~3.2 eV and 3.0 eV for anatase and rutile, respectively), which makes it active only under ultraviolet (UV), i.e. it uses less than ~5% solar energy) [3]. To enhance the solar energy conversion efficiency of TiO₂, one strategy is

to extend its photoresponse to visible light, which comprises a greater portion ($\sim 45\%$) of the solar spectrum [4, 5]. This can be achieved by several strategies such as doping with impurities [6-11], coupling with dyes [12-14] and sensitizing with semiconductors [15, 16] that have proper conduction band levels. Recently, narrow band gap semiconductors such PbS [17], CdSe [18], ZnS [19] and CdS [20, 21] have been successfully studied as sensitizer for TiO₂ nanostructures that exhibit obviously enhanced response under visible light. For instance, CdS has a low band gap (~2.4 eV) and a relatively high absorption coefficient in the visible light region, and its conduction band is more negative than that of TiO_2 [22]. The electrons generated in the CdS by the visible light radiation transfer to TiO₂ thus separating the photon-induced electrons and holes in the CdS and TiO₂, respectively. These properties make CdS highly desirable for use in photoelectrochemisty and photocatalysis in comparion with other semiconductors [23]. CdS nanoparticles (NPs) have several advantages, namely a

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high extinction coefficient, spectral tunability by size, and good stability. They can be grown directly on TiO₂ by electrodeposition [24], chemical bath deposition (CBD) [25], and successive ion layer adsorption and reaction (SILAR) [26, 27]. For the SILAR method, the amount of the CdS NPs can be easily controlled by altering the number of deposition cycles. To obtain good electron-hole separation efficiency is crucial for enhancing the photocatalytic [28]. For example, reducing the thickness of the TiO₂ could decrease the diffusion pathway of the photo-generated holes to the electrode/electrolyte interface to avoid recombining with photo-generated electrons as TiO_2 has a short hole diffusion length (~10 nm) [29]. Fabricating nanostructures such as nanoparticles, porous nanospheres, nanotubes, nanowires, nanobelts, nanoneedles, and nanorods is a promising way to enhance solar energy conversion efficiency of TiO2, as nanostructures exhibit many desirable characteristics for effective photocatalysis such as efficient and tunable optical absorption, large surface areas, short charge carrier diffusion lengths and low reflectivity [30]. Onedimension (1D) nanostructures such as nanorods can be obtained by organometallic chemical vapor deposition (OMCVD) [31], hydrothermal processes [32], glancing angle deposition (GLAD) [33] and oblique angle deposition (OAD) [34]. The OAD technique is a unique physical vapor deposition process used to fabricate large area, uniform, aligned nanorod arrays with controlled porosity, where the vapor flux is incident onto a substrate at a large angle θ ($\theta > 70^\circ$) with respect to the substrate normal. Due to a geometric shadowing effect, wellaligned and separated nanorod arrays can be produced [35]. The film resulting from the OAD technique presents very open and porous microstructure where nanometer-size columns with a high internal porosity are separated by wide pores that extend from the substrate up to the film surface [36], which is very advantageous in increasing the interface between nanorod and solution. Moreover, the porosity can be readily tuned by varying the oblique angle and various substrates such as glass, F-doped SnO₂ (FTO), Si, etc, can be used.

To the aim of improving the TiO_2 properties under visible light, fabricating large area uniform TiO_2 nanorod arrays (TiO_2 NRAs) decorated with CdS NPs is a promising way to harvest solar energy and enhance solar energy conversion efficiency by coupling the traits of TiO_2 nanorods and CdS nanoparticles.

In this paper, we obtain TiO_2 NRAs by annealing Ti NRAs that are fabricated using the OAD technique, and CdS particles are deposited on TiO_2 NRAs by successive ion layer adsorption and reaction (SILAR). The photocatalytic and photoelectrochemical properties of the TiO₂ NRAs/CdS film under visible light improve noticeably compared to the bare TiO₂ NRAs and CdS films, respectively.

2. Materials and methods

2.1. TiO₂ NRAs fabrication

The Ti NRAs were deposited on planar Si substrates and transparent FTO substrates (20 Ω per square) by the oblique

angle deposition technique (OAD) described elsewhere [37], and the films deposited on the Si substrates were used for scanning electron microscopy (SEM) and Raman measurements. The substrates were sequentially cleaned in acetone and alcohol by ultrasonic, and then rinsed in deionized water for 5 min each. The system was pumped down to a base pressure of 4×10^{-8} Torr, and then the Ti film was deposited on the substrate at a deposition rate of 0.5 nm s^{-1} , which was monitored by a quartz crystal microbalance. To produce the films of aligned Ti NRAs, the incident beam of the Ti flux was set at $\sim 85^{\circ}$ with respect to the substrate normal at room temperature. In order to obtain TiO₂ NRAs, the Ti NRAs were oxidized in a tube furnace, the furnace was heated up to 450 °C for 2 h at a rate of 5 °C min⁻¹ in ambient atmosphere, resulting in crystalline TiO2 NRAs with good photocatalytic activity.

2.2. CdS NPs deposition on TiO₂ NRAs

CdS NPs were deposited on TiO₂ NRAs via a successive ionic layer adsorption and reaction (SILAR) method with slight modification, as previously reported [21]. Briefly, the TiO₂ NRAs substrates were successively exposed to Cd(Ac)₂ and Na₂S solutions, respectively, to deposit CdS nanocrystallites. The TiO₂ NRAs were immersed in a Cd(Ac)₂ (0.05 M) solution for 30 s, and were then rinsed with deionized water and immersed in a solution of Na₂S (0.05 M) for another 30 s followed by another rinsing with deionized water. This SILAR process was repeated until the desired deposition of CdS nanocrystallites was achieved.

2.3. Measurements

2.3.1. Experimental setup. The surface morphology was observed by field emission scanning electron microscopy (SEM, JEOL-7001F). A Rigaku 2500 x-ray diffractometer was employed to investigate the crystallographic characteristics of the TiO₂ NRAs/CdS NPs. The TiO₂ NRAs/CdS NPs were also characterized by transmission electron microscope (TEM, JEOL-2010F). Absorption spectra were recorded using а UV-vis spectrophotometer (PerkinElmer Lambda 950). The Raman and photoluminescence (PL) spectra were recorded using Raman spectrometer (LabRAM ARMIS) under 488 nm and 325 nm excitation, respectively.

2.3.2. Photocatalytic discoloration of methyl orange. Methyl orange (MO) was considered as a model contaminant in the purification of dye wastewater. The prepared samples ($15 \text{ mm} \times 15 \text{ mm}$) were placed in a quartz cell containing 10 mL of MO (5μ M) aqueous solution. The photocatalyst was 5 cm away from the quartz window. The relative concentration of MO in the solution was determined by comparing its UV–vis absorption intensity with that of the initial MO solution at 462 nm.

The photocurrent intensity versus potential (*I–V* curve) measurements were carried out in a 250 mL quartz cell connected to an electrochemistry workstation (CHI 660,

Shanghai Chenhua Instrument). A three-electrode assembly was adopted for the test, which included a prepared TiO₂ NRAs/CdS NPs as a working electrode, a Pt foil as a counter electrode, a KCl saturated Ag/AgCl as a reference electrode and 0.1 M Na₂S as an electrolyte. The working electrode was illuminated with a 300 W Xe lamp. An ultraviolet cutoff filter was inserted between the light source and the quartz cell to exclude UV light with the wavelength shorter than 420 nm. Photocurrent densities were measured in the light on–off process with a pulse of 30 s using the potentiostatic technique [38] under visible light illumination of 130 mW cm⁻² and 0 V bias versus Ag/AgCl electrode.

3. Results and discussion

Figure 1(a) shows a typical top-view SEM image of Ti NRAs prepared by the OAD technique by electron beam evaporation, and the inset shows a typical tilted angle-view SEM image of the NRAs. One sees that the Ti nanorods are 50–90 nm in diameter, \sim 220 nm in length, and well separated. Figure 1(b) shows a typical top-view SEM image of the TiO₂ NRAs obtained by oxidizing the Ti NRAs at 450 °C for 2 h in air, and the inset shows a SEM image of the TiO₂ NRAs at a tilted angle of 45° . It is seen that the TiO₂ nanorods kept the shape and dimensions of Ti nanorods. Figures 1(c)-(f) show typical top-view SEM images of the TiO₂ NRAs after the depositing of CdS NPs by 5, 10, 15, and 20 SILAR cycles deposition, respectively. The SILAR method is an effective way to deposit CdS nanocrystallites on TiO₂ nanorods [39, 40]. With an increase in the deposition cycle, there are two different types of CdS nanocrystal growth: one is the formation of new crystallites and the other is the growth of smaller crystallites into larger ones [21]. It is seen in figure 1(e) that after 15 cycles, large CdS crystallites (~40-50 nm) consisting of several nanocrystallites were deposited on the TiO₂ nanorods. After 20 cycles, as shown in figure 1(f), the CdS nanocrystallites aggregated and formed larger crystallites (~60-70 nm). It is observed that after CdS deposition by 20 cycles, the decorated TiO₂ nanorods are still separated. However, as shown in figure S1, the entire surface of the TiO₂ NRAs were covered by a film consisting of larger CdS crystallites, after 25 cycles of deposition.

Figure 2(a) displays the XRD patterns of the TiO₂ NRAs deposited with CdS NPs for different SILAR cycles. The diffraction peak at $2\theta = 27.3^{\circ}$ corresponding to the (110) crystal planes of the rutile phase (JPCDS No. 21-1276) is observed. The presence of a broad XRD peak is an indication of small crystallite size in the nanoscale range, affirming the nanocrystalline nature of the nanorods. To clarify the structure of as-prepared TiO₂ NRAs, we measured the as-prepared samples using XRD with the step scanning method. The XRD measurement was performed with a scanning step of 0.01° and with a dwell time of 2 s in the scanning range of 23.5°–28.5°. The corresponding XRD pattern of the as-prepared sample was shown in the inset of figure 2(a), which displays two distinctive peaks at 25.3° and 27.3°, corresponding to anatase (101) and rutile (110), respectively. In the

original XRD patterns measured with the glancing angle x-ray diffraction (GXRD) method, only one broad peak centered at \sim 27.3°Can be observed, with which the diffraction peak related to the anatase (101) plane is superimposed.

It is noticed that the peak at $2\theta = 27.3^{\circ}$ shifts to a lower angle gradually with increasing SILAR cycles. After 25 SILAR cycles deposition, a peak at $2\theta = 26.5^{\circ}$ is formed, indicating a preferred orientation along the (111) plane of the cubic phase CdS (JCPDS No. 89-0440). These result confirm the successful deposition of CdS on TiO₂ NRAs.

The Raman spectrum of TiO₂ NRAs is shown in figure 2(b). The anatase and rutile structure belongs to *I*41/ amd space group and *P*42/mnm tetragonal space group, respectively. The first peak at 144 cm⁻¹ as a characteristic of anatase is formed in the as-prepared TiO₂ NRAs. The peak at 613 cm⁻¹ can be assigned to the Raman active modes of the rutile [41, 42]. One sees that the TiO₂ NRAs consist of a mixture of anatase and rutile nanocrystallites, which will be further verified by TEM.

The growth of CdS NPs on TiO2 NRAs by SILAR was investigated by high-resolution transmission electron microscopy (HRTEM) analysis. Figures 3(a), (b) show HRTEM images of TiO₂ nanorods obtained by oxidizing Ti nanorods. The TiO₂ nanorods are polycrystalline, and consist of both the anatase and the rutile phases. The presence of the anatase-rutile heterojunction in the nanorods may help the rutile particles to efficiently collect photon-induced electrons from the anatase particles to reduce the charge recombination [43]. Figures 3(c), (d) show HRTEM images of TiO_2 nanorods decorated with CdS NPs after 15 cycles of SILAR. It is seen clearly that ultrafine CdS particles with a diameter of ~5 nm were on the nanorod, forming heterojunctions of CdS and TiO_2 . After 25 SILAR cycles, as shown in figures 3(e), (f), the TiO₂ nanorods are covered by a CdS film consisting of large CdS NPs (~50 nm). Energy dispersive x-ray spectrum analysis was also carried out for the CdS NPs decorated TiO₂ nanorods. The results are shown in figure S2. It shows that the Ti/Cd ratio was ~ 1.50 and ~ 0.77 in areas marked by the red rectangles in figures 3(c) and (e), respectively, confirming that more CdS NPs were grown on TiO2 NRAs at a higher number of deposition cycles.

Figure 4(a) shows the Raman spectra of TiO_2 NRAs coated with CdS particles using different numbers of SILAR cycles. One sees that the TiO₂ NRAs consist of a mixture of anatase and rutile nanocrystallites, which is in agreement with the HRTEM observation; see figure 3(b). The three strong Raman peaks located around 303, 606, and 909 cm⁻¹ are assigned, respectively, to the first-, second-, and third-order longitudinal optical (LO) phonon modes of CdS [44, 45]. The peaks located at ~ 521 and 979 cm^{-1} are from the silicon substrates [46, 47]. The increase in the intensity of the Raman peaks for CdS suggests that more CdS NPs were grown on the TiO₂ NRAs, by increasing the SILAR cycles. The optical absorption property of TiO2 NRAs decorated by CdS NPs was measured and is shown in figure 4(b). The inset of figure 4(b) is an optical image of the TiO_2 NRAs decorated by CdS NPs, showing clearly the color change. The undecorated TiO₂ NRAs exhibited absorption in the UV region



Figure 1. SEM images of the samples: (a) Ti NRAs; (b) TiO₂ NRAs obtained from oxidation of Ti NRAs. The insets in (a) and (b) are the images recorded at a tilt angle of 45° ; after (c) 5, (d) 10, (e) 15, and (f) 20 SILAR cycles of CdS deposition.

(at < 380 nm), and a weak absorption in the visible light region which was attributed to the scattering of light caused by pores in the NRAs [38]. Because of the deposition of CdS NPs, all decorated TiO₂ NRAs exhibited strong light absorption in a wide region, from 380 nm to 600 nm. In agreement with the color change of the samples (see inset of figure 4(b)) and Raman analysis (see figure 4(a)), the absorption capability in the visible light of the CdS-decorated TiO₂ NRAs was enhanced monotonically by increasing the SILAR cycles. This may suggest an enhancement in the photocatalytic activity of the decorated TiO₂ NRAs in the visible light.

The photocatalytic activity of CdS-decorated TiO₂ NRAs was examined by the discoloration of methyl orange upon irradiation with visible light. According to Beer's law, the intensity of the $\lambda = 462$ nm absorbance peak of methyl orange is proportional to the solution concentration, if it is below 0.8 [48]. The discoloration rate η can be calculated by

 $\eta = 1 - \frac{A(t)}{A_0}$, where A_o and A(t) are the absorbance at 462 nm, at the irradiation time of 0 and t, respectively. Figure 5 plots the discoloration rate of methyl orange as a function of time, using the CdS-decorated TiO₂ NRAs as a photocatalyst. One sees that using the undecorated TiO₂ NRAs as a photocatalyst, the discoloration rate was only 3.2% even after 150 min of irradiation; this is attributed to the photobleaching process [49]. Enhancement was observed using CdS-decorated TiO₂ NRAs as photocatalyst; for example, the discoloration rate was 12.6% when using CdS-decorated TiO₂ NRAs by 5 SILAR cycles, and it was 42.0% if using TiO₂ NRAs decorated by 20 SILAR cycles. However it is also observed when using the TiO2 NRAs decorated by 25 SILAR cycles as a catalyst, though more CdS NPs were grown (see figures 1-3), and the discoloration rate decreased, i.e. it was down to 39.0%.

We have performed photoelectrochemical I-V, photocurrent measurements, and PL measurements to better



Figure 2. (a) X-ray diffraction (XRD) patterns of the TiO₂ NRAs/ CdS NPs. Inset is the XRD pattern of TiO₂ NRAs by step scanning method in the scanning range of 23.5° – 28.5° ; (b) Raman spectrum of TiO₂ NRAs. A: anatase, R: rutile, Si: Si substrate.

understand the photocatalytic performance of these TiO_2 NRAs decorated by CdS NPs. Figure 6(a) shows the I-Vcurves measured for CdS-decorated TiO₂ NRAs. It is seen that the open circuit potential (Voc), which corresponds to the difference in the apparent Fermi level between the TiO₂ NRAs/CdS NPs and the reference electrode [21], is very dependent on the CdS decoration. It was ~ -0.42 V for TiO₂ NRAs without CdS decoration, and became more negative after decorated with CdS NPs; for instance, it was ~ -1.14 V when decorated by 5 SILAR cycles, and was ~ -1.21 V when decorated by 20 SILAR cycles. One may also notice that when decorated by 25 cycles, it became less negative than -1.21 V. Following the literature, the shift of the Fermi level towards the more negative potentials indicates a better charge carrier separation and electron accumulation in semiconductor-semiconductor heterojunctions [21, 50-52].

Figure 6(b) plots the photocurrent of the CdS-decorated TiO₂ NRAs versus the incident light irradiation time. It is observed that all the samples exhibited a quick response to the on/off of the incident light, and that the photocurrent was

larger for samples decorated by more SILAR cycles. The exception is for the sample decorated by 25 SILAR cycles, which had a smaller photocurrent in comparison with the sample decorated by 20 SILAR cycles. It is well known that a higher photocurrent suggests a higher efficiency in the separation of electrons and holes [53], thus suggesting a better photocatalytic activity. We also fabricated the CdS NPs on bare FTO and Ti NRAs under the same conditions as the CdS NPs deposition on TiO₂ NRAs. The photocurrent density versus time coupling irradiation on/off is shown in figure S3. Similar quick responses to the on/off of the incident light are observed in Ti/CdS NPs NRAs due to the properties of CdS NPs; however, the photocurrent density of these is much lower than that of TiO₂ NRAs/CdS NPs, indicating the TiO₂ NRAs play a role in enhancing the separation efficiency of electrons and holes rather than a temperate.

The PL technique is an effective way to study the efficiency of the charge carrier trapping, migration and transfer, as PL signals result from the recombination of photo-induced carriers. Figure 6(c) shows the PL spectra of the CdS-decorated TiO₂ NRAs. The peaks at \sim 425, \sim 530 and \sim 630 nm can be ascribed to the self-trapped excitons [54] and the oxygen vacancies (V_o) in TiO₂ [55, 56] and to the sulfur-deficient defects in CdS nanocrystallites [57], respectively. One sees that for samples decorated by more SILAR cycles, the PL intensity was weaker. The exception is for the sample decorated by 25 cycles, which exhibited a stronger PL intensity than the one decorated by 20 cycles. It has been recognized that a lower PL intensity suggests a lower recombination rate of the photo-induced electron-hole pairs [58], and thus a better photocatalytic performance. This is exactly the case we observed here (see figure 4).

The optical property of TiO₂ NRAs/CdS NPs irradiated with visible light irradiation for 150 min was measured and is shown in figure S4(a). After irradiation, the absorbance of all samples decreases compared to that of the unirradiated sample due to the photo-corrosion in CdS, photo-corrosion occurs when excited electrons and holes are trapped by surface states under visible light irradiation under ambient conditions [59]. To clearly compare the photostability of the TiO₂ NRAs/CdS NPs, we depicted the decreasing rate of optical absorbance intensity at 430 nm before and after irradiation as the corrosion rate. It shows clearly that during an exposure time of 150 min, the corrosion rate is more than 30% for the TiO₂ NRAs deposited with different SILAR cycles CdS NPs. The photo-corrosion for CdS pollutes the water solution, so it is very necessary to avoid photo-corrosion in future work.

For a semiconductor excited by photons with energies higher than its band gap, electrons are excited from the valence band into the unoccupied conduction band, generating excited electrons in the conduction band and positive holes in the valence band. As shown in figure 7, when illuminated by visible light, CdS effectively excites electrons and holes. The conduction band of CdS is more positive than that of TiO₂ resulting in a local electric field. As a result, the excited electrons can quickly transfer from the CdS to the TiO₂ conduction band, whereas the generated holes accumulate in the valence band of CdS to form the holes' center.



Figure 3. TEM images and HRTEM images: (a), (b) TiO₂ NRAs; (c), (d) 15 SILAR cycles TiO₂ NRAs/CdS NPs; (e), (f) 25 SILAR cycles TiO2 NRAs/CdS NPs.

Consequently, the excited electron/hole pairs could be separated effectively, which contributed to the improvement of photoelectrochemical properties of TiO_2 NRAs/CdS NPs. During the irradiation process, the CdS coupled TiO_2 NRAs prolong the lifetime of the photo-induced electrons and holes due to their efficient separation, resulting in an efficient oxidation-reduction reaction, so that the photoactivity can be enhanced. The accumulated electrons in the conduction band of TiO₂ can be transferred to oxygen to form active oxygen species (e.g. \cdot O₂), which could be further reduced to highly reactive hydroxyl radicals (OH) [60]. The formed hydroxyl radicals (OH) could further decompose the organic dye MO to



Figure 4. (a) Raman spectra of TiO_2 NRAs/CdS NPs; (b) Absorption spectra of the TiO_2 NRAs/CdS NPs. Inset is the optical photograph of the TiO_2 NRAs/CdS NPs.



Figure 5. Visible light ($\lambda \ge 420$ nm) discoloration of MO using TiO₂ NRAs/CdS NPs as catalyst.

intermediates or mineralized products. Furthermore, the holes accumulated in the valence band of CdS could be consumed by participating in a direct reaction with MO molecules to



Figure 6. (a) *I–V* characteristics of the TiO₂ NRAs/CdS NPs; (b) current versus time measurements of TiO₂ NRAs/CdS NPs under 0 V versus Ag/AgCl bias; (c) PL spectra of TiO₂/NRAs CdS NPsexcited by 325 nm.

form intermediates or mineralized products [61]. In this study, the discoloration of MO is due to a small part of the photobleaching process, but efficiency depends on the density of the electrons and holes, i.e. the more density, the higher



Figure 7. Schematic of light absorption, electrons separation, transfer and degradation of MO process for TiO₂ NRAs/CdS NPs.

efficiency. Therefore, the photoactivity of TiO_2 NRAs/CdS NPs has a positive correlation with the density of the photocurrent, which agrees with the experimental results.

4. Conclusions

In summary, TiO_2 NRAs were fabricated by oxidizing Ti NRAs obtained by oblique angle deposition, CdS NPs deposited on TiO_2 NRAs via successive ion layer adsorption and reaction forming heterojunctions of TiO2 NRAs/CdS NPs. The TiO₂ NRAs/CdS NPs composites exhibit both excellent visible light photoelectrochemical and photocatalytic properties due to excited electrons injected into TiO₂ resulting from the efficient electron–hole separation, and the TiO₂ NRAs decorated with 20 SILAR cycles CdS display the best properties. However, aggregate CdS NPs exhibiting a poorer performance were attributed to lower electron–hole separation with increasing the SILAR cycles. Forming heterojunctions of CdS NPs and TiO₂ NRAs provides a promising way to fabricate material applied in the solar energy conversion and purification of wastewater.

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References

- [1] Fujishima A 1972 Electrochemical photolysis of water at a semiconductor electrode *Nature* **238** 37–8
- [2] Yuan R, Chen T, Fei E, Lin J, Ding Z, Long J, Zhang Z, Fu X, Liu P and Wu L 2011 Surface chlorination of TiO₂-based photocatalysts: a way to remarkably improve photocatalytic activity in both UV and visible region ACS Catalysis 1 200–6

- Barborini E, Conti A M, Kholmanov I, Piseri P, Podestà A, Milani P, Cepek C, Sakho O, Macovez R and Sancrotti M 2005 Nanostructured TiO₂ films with 2 eV optical gap *Adv. Mater.* 17 1842–6
- [4] Abe R 2010 Recent progress on photocatalytic and photoelectrochemical water splitting under visible light irradiation J. Photochem Photobiol. C 11 179–209
- [5] Kudo A and Miseki Y 2009 Heterogeneous photocatalyst materials for water splitting *Chem. Soc. Rev.* 38 253–78
- [6] Jagadale T C, Takale S P, Sonawane R S, Joshi H M, Patil S I, Kale B B and Ogale S B 2008 N-doped TiO₂ nanoparticle based visible light photocatalyst by modified peroxide sol –gel method J. Phys. Chem. C 112 14595–602
- [7] Chen D, Jiang Z, Geng J, Wang Q and Yang D 2007 Carbon and nitrogen co-doped TiO₂ with enhanced visible-light photocatalytic activity *Indust. Eng. Chem. Res.* 46 2741–6
- [8] Yu J C, Ho W, Yu J, Yip H, Wong P K and Zhao J 2005 Efficient visible-light-induced photocatalytic disinfection on sulfur-doped nanocrystalline titania *Environ. Sci. Tech.* 39 1175–9
- [9] Zhou M, Yu J and Cheng B 2006 Effects of Fe-doping on the photocatalytic activity of mesoporous TiO₂ powders prepared by an ultrasonic method *J. Hazard Mater.* 137 1838–47
- [10] In S, Orlov A, Berg R, García F, Pedrosa-Jimenez S, Tikhov M S, Wright D S and Lambert R M 2007 Effective visible light-activated B-doped and B, N-codoped TiO₂ photocatalysts J. Am. Chem. Soc. **129** 13790–1
- [11] Liu S, Guo E and Yin L 2012 Tailored visible-light driven anatase TiO₂ photocatalysts based on controllable metal ion doping and ordered mesoporous structure *J. Mater. Chem.* 22 5031–41
- [12] Park Y, Lee S-H, Kang S O and Choi W 2010 Organic dyesensitized TiO₂ for the redox conversion of water pollutants under visible light *Chem. Commun.* 46 2477–9
- [13] Reisner E, Powell D J, Cavazza C, Fontecilla-Camps J C and Armstrong F A 2009 Visible light-driven H2 production by hydrogenases attached to dye-sensitized TiO₂ nanoparticles *J. Am. Chem. Soc.* **131** 18457–66
- [14] Kim W, Tachikawa T, Majima T and Choi W 2009 Photocatalysis of dye-zensitized TiO₂ nanoparticles with thin overcoat of Al2O3: enhanced activity for H2 production and dechlorination of CCl4 J. Phys. Chem. C 113 10603–9
- [15] Liu B, Wang D, Zhang Y, Fan H, Lin Y, Jiang T and Xie T 2013 Photoelectrical properties of Ag2S quantum dotmodified TiO₂ nanorod arrays and their application for photovoltaic devices *Dalton Trans.* **42** 2232–7
- [16] Wang M, Sun L, Lin Z, Cai J, Xie K and Lin C 2013 p–n heterojunction photoelectrodes composed of Cu2O-loaded TiO₂ nanotube arrays with enhanced photoelectrochemical and photoelectrocatalytic activities *Energy Environ. Sci.* 6 1211
- [17] Lee H, Leventis H C, Moon S J, Chen P, Ito S, Haque S A, Torres T, Nüesch F, Geiger T and Zakeeruddin S M 2009 PbS and CdS quantum dot–sensitized solid–state solar cells: old concepts, new results Adv. Funct. Mater. 19 2735–42
- [18] Lee H J, Bang J, Park J, Kim S and Park S-M 2010 Multilayered semiconductor (CdS/CdSe/ZnS)–sensitized TiO₂ mesoporous solar cells: all prepared by successive ionic layer adsorption and reaction processes *Chem. Mater.* 22 5636–43
- [19] Guijarro N, Campiña J M, Shen Q, Toyoda T, Lana-Villarreal T and Gómez R 2011 Uncovering the role of the ZnS treatment in the performance of quantum dot sensitized solar cells *Phys. Chem. Chem. Phys.* 13 12024–32
- [20] Li G-S, Zhang D-Q and Yu J C 2009 A new visible-light photocatalyst: CdS quantum dots embedded mesoporous TiO₂ Environ. Sci. Tech. 43 7079–85

- [21] Baker D R and Kamat P V 2009 Photosensitization of TiO₂ nanostructures with CdS quantum dots: particulate versus tubular support architectures Adv. Funct. Mater. 19 805–11
- [22] Das K and De S 2009 Optical properties of the type-II core-shell TiO₂@ CdS nanorods for photovoltaic applications J. Phys. Chem. C 113 3494–501
- [23] Liu Y, Zhou H, Zhou B, Li J, Chen H, Wang J, Bai J, Shangguan W and Cai W 2011 Highly stable CdS-modified short TiO₂ nanotube array electrode for efficient visible-light hydrogen generation *Int. J. Hydrogen Energy* **36** 167–74
- [24] Wang C, Sun L, Yun H, Li J, Lai Y and Lin C 2009 Sonoelectrochemical synthesis of highly photoelectrochemically active TiO₂ nanotubes by incorporating CdS nanoparticles *Nanotechnology* 20 295601
- [25] Lin S-C, Lee Y-L, Chang C-H, Shen Y-J and Yang Y-M 2007 Quantum-dot-sensitized solar cells: assembly of CdSquantum-dots coupling techniques of self-assembled monolayer and chemical bath deposition *Appl. Phys. Lett.* **90** 143517
- [26] Luo J, Ma L, He T, Ng C F, Wang S, Sun H and Fan H J 2012 TiO₂/(CdS, CdSe, CdSeS) nanorod heterostructures and photoelectrochemical properties *J. Phys. Chem.* C 116 11956–63
- [27] Cheng S, Fu W, Yang H, Zhang L, Ma J, Zhao H, Sun M and Yang L 2012 Photoelectrochemical performance of multiple semiconductors (CdS/CdSe/ZnS) cosensitized TiO₂ photoelectrodes *J. Phys. Chem.* C **116** 2615–21
- [28] Shaislamov U and Yang B L 2013 CdS-sensitized singlecrystalline TiO₂ nanorods and polycrystalline nanotubes for solar hydrogen generation *J. Mater. Res.* 1 1–6
- [29] Salvador P 1984 Hole diffusion length in n-TiO 2 single crystals and sintered electrodes: photoelectrochemical determination and comparative analysis J. Appl. Phys. 55 2977–85
- [30] Zhou H, Qu Y, Zeid T and Duan X 2012 Towards highly efficient photocatalysts using semiconductor nanoarchitectures *Energy Environ. Sci.* 5 6732–43
- [31] Pradhan S K, Reucroft P J, Yang F and Dozier A 2003 Growth of TiO₂ nanorods by metalorganic chemical vapor deposition J. Cryst. Growth 256 83–8
- [32] Nian J-N and Teng H 2006 Hydrothermal synthesis of singlecrystalline anatase TiO₂ nanorods with nanotubes as the precursor J. Phys. Chem. B 110 4193–8
- [33] González-García L, González-Valls I, Lira-Cantu M, Barranco A and González-Elipe A R 2011 Aligned TiO₂ nanocolumnar layers prepared by PVD-GLAD for transparent dye sensitized solar cells *Energy Environ. Sci.* 4 3426–35
- [34] He Y, Zhang Z and Zhao Y 2008 Optical and photocatalytic properties of oblique angle deposited TiO₂ anorod array *J. Vac. Sci. Technol.* B 26 1350–8
- [35] Wolcott A, Smith W A, Kuykendall T R, Zhao Y and Zhang J Z 2009 Photoelectrochemical water splitting using dense and aligned TiO₂ nanorod arrays *Small* 5 104–11
- [36] Krause K M, Taschuk M T, Harris K D, Rider D A, Wakefield N G, Sit J C, Buriak J M, Thommes M and Brett M J 2009 Surface area characterization of obliquely deposited metal oxide nanostructured thin films *Langmuir* 26 4368–76
- [37] Xie Z, Zhang Y, Liu X, Wang W, Zhan P, Li Z and Zhang Z 2013 Visible light photoelectrochemical properties of Ndoped TiO₂ nanorod arrays from TiN J. Nanomater. 2013 930950
- [38] Li G, Wu L, Li F, Xu P, Zhang D and Li H 2013 Photoelectrocatalytic degradation of organic pollutants via a CdS quantum dots enhanced TiO₂ nanotube array electrode under visible light irradiation *Nanoscale* 5 2118–25
- [39] Lee H J, Chen P, Moon S-J, Sauvage F D R, Sivula K, Bessho T, Gamelin D R, Comte P, Zakeeruddin S M and

Seok S I 2009 Regenerative PbS and CdS quantum dot sensitized solar cells with a cobalt complex as hole mediator *Langmuir* **25** 7602–8

- [40] Zewdu T, Clifford J N, Hernández J P and Palomares E 2011 Photo-induced charge transfer dynamics in efficient TiO₂/CdS/ CdSe sensitized solar cells *Energy Environ. Sci.* 4 4633–8
- [41] Ma H L, Yang J Y, Dai Y, Zhang Y B, Lu B and Ma G H 2007 Raman study of phase transformation of TiO₂ rutile single crystal irradiated by infrared femtosecond laser *Appl. Surf. Sci.* 253 7497–500
- [42] Mali S S, Desai S K, Dalavi D S, Betty C A, Bhosale P N and Patil P S 2011 CdS-sensitized TiO₂ nanocorals: hydrothermal synthesis, characterization, application *Photochem. Photobiol. Sci.* 10 1652–8
- [43] Sun P, Zhang X, Wang C, Wei Y, Wang L and Liu Y 2013 Rutile TiO₂ nanowire array infiltrated with anatase nanoparticles as photoanode for dye-sensitized solar cells: enhanced cell performance via the rutile–anatase heterojunction *J. Mater. Chem.* A 1 3309–14
- [44] Mali S, Desai S, Dalavi D, Betty C, Bhosale P and Patil P 2011 CdS-sensitized TiO₂ nanocorals: hydrothermal synthesis, characterization, application *Photochem. Photobiol. Sci.* 10 1652–8
- [45] Wang Z, Gong J, Duan J, Huang H, Yang S, Zhao X, Zhang R and Du Y 2006 Direct synthesis and characterization of CdS nanobelts *Appl. Phys. Lett.* 89 033102–3
- [46] Dai C, Chuu D and Hsieh W 1991 Raman intensity enhancement of the Si peak by CdS thin films *Appl. Phys. Lett.* 59 3273–5
- [47] Baleva M, Zlateva G, Atanassov A, Abrashev M and Goranova E 2005 Resonant Raman scattering in ion-beamsynthesized Mg_ {2} Si in a silicon matrix *Phys. Rev. B* 72 115330
- [48] Li Z, Zhu Y, Zhou Q, Ni J and Zhang Z 2012 Photocatalytic properties of TiO₂ thin films obtained by glancing angle deposition *Appl. Surf. Sci.* 258 2766–70
- [49] Cheng P, Deng C, Gu M and Shangguan W 2007 Visible-light responsive zinc ferrite doped titania photocatalyst for methyl orange degradation J. Mater. Sci. 42 9239–44
- [50] Subramanian V, Wolf E E and Kamat P V 2003 Green emission to probe photoinduced charging events in ZnO-Au nanoparticles. Charge distribution and fermi-level equilibration J. Phys. Chem. B 107 7479–85
- [51] Jakob M, Levanon H and Kamat P V 2003 Charge distribution between UV-irradiated TiO₂ and gold nanoparticles: determination of shift in the Fermi level *Nano Lett.* **3** 353–8
- [52] Wood A, Giersig M and Mulvaney P 2001 Fermi level equilibration in quantum dot-metal nanojunctions *J. Phy. Chem.* B 105 8810–5
- [53] Liu Y, Xie C, Li J, Zou T and Zeng D 2012 New insights into the relationship between photocatalytic activity and photocurrent of TiO₂/WO₃ nanocomposite *Appl. Catal.* A 433-434 81–7
- [54] Lei Y, Zhang L, Meng G, Li G, Zhang X, Liang C, Chen W and Wang S 2001 Preparation and photoluminescence of highly ordered TiO nanowire arrays *Appl. Phys. Lett.* 78 1125
- [55] Santara B, Giri P, Imakita K and Fujii M 2013 Evidence of oxygen vacancy induced room temperature ferromagnetism in solvothermally synthesized undoped TiO₂ nanoribbons *Nanoscale* 5 5476–88
- [56] Shi J, Chen J, Feng Z, Chen T, Lian Y, Wang X and Li C 2007 Photoluminescence characteristics of TiO₂ and their relationship to the photoassisted reaction of water/methanol mixture *The J. Phys. Chem.* C **111** 693–9
- [57] Yang Y, Chen H, Mei Y, Chen J, Wu X and Bao X 2002 CdS nanocrystallites prepared by chemical and physical templates Acta Mater. 50 5085–90

- [58] Liqiang J, Yichun Q, Baiqi W, Shudan L, Baojiang J, Libin Y, Wei F, Honggang F and Jiazhong S 2006 Review of photoluminescence performance of nano-sized semiconductor materials and its relationships with photocatalytic activity *Sol. Energy Mater.* C 90 1773–87
- [59] Xu L, Wang L, Huang X, Zhu J, Chen H and Chen K 2000 Surface passivation and enhanced quantum-size effect and photo stability of coated CdSe/CdS nanocrystals *Physica* E 8 129–33
- [60] Jin S, Li Y, Xie H, Chen X, Tian T and Zhao X 2012 Highly selective photocatalytic and sensing properties of 2Dordered dome films of nano titania and nano Ag2+ doped titan J. Mater. Chem. 22 1469–76
- [61] Xie Y, Ali G, Yoo S H and Cho S O 2010 Sonication-assisted synthesis of CdS quantum-dot-sensitized TiO₂ nanotube arrays with enhanced photoelectrochemical and photocatalytic activity ACS Appl. Mater. Interfaces 2 2910–4